INTEGRATED CIRCUITS

DATA SHEET



74F242

Quad transceiver, inverting (3-State) **74F243**

Quad transceiver (3-State)

Product specification

1990 Aug 31

IC15 Data Handbook

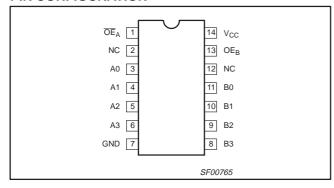




Transceivers 74F242/74F243

74F242 Quad Transceiver, Inverting (3-State) 74F243 Quad Transceiver (3-State)

PIN CONFIGURATION



TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F242	4.3ns	31.2mA
74F243	4.0ns	66mA

ORDERING INFORMATION

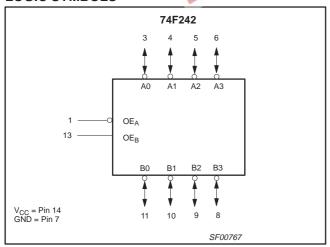
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V $\pm 10\%$, T_{amb} = 0°C to +70°C	PKG DWG #
14-pin plastic DIP	N74F242N, N74F243N	SOT27-1
14-pin plastic SO	N74F242D, N74F243D	SOT108-1

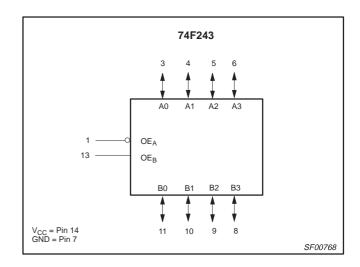
INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
An, Bn	Data inputs (74F242)	3.5/1.67	70μA/1.0mA
An, Bn	Data inputs (74F243)	3.5/2.67	70μA/1.6mA
ŌĒĄ	Output enable input (active Low)	1.0/1.67	20μA/1.0mA
OE _B	Output enable input	1.0/1.67	20μA/1.0mA
An, Bn	Data outputs	750/106.7	15mA/64mA

NOTE: One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

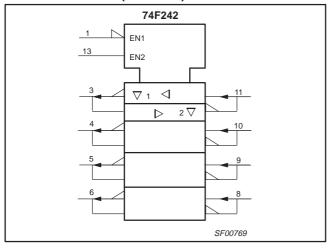
LOGIC SYMBOLS

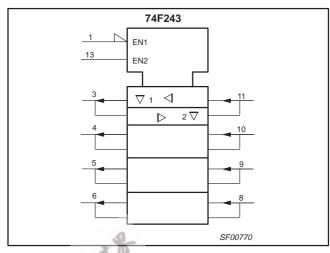


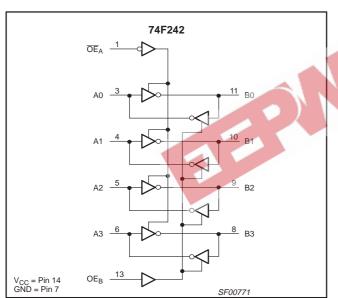


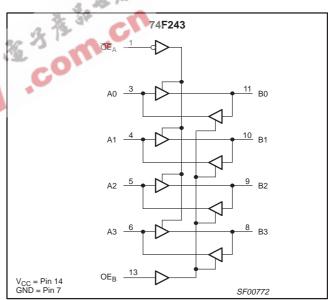
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LOGIC SYMBOLS (IEEE/IEC)









LOGIC DIAGRAMS FUNCTION TABLE, 74F242

INP	JTS	OUTF	PUTS
ŌĒĄ	OE _B	An	Bn
L	L	INPUT	B= A
Н	L	Z	Z
L	Н	а	а
Н	Н	A=B	INPUT

H = High voltage level
L = Low voltage level
Z = High impedance "off" state
a = This condition is not allowed due to excessive currents

FUNCTION TABLE, 74F243

INP	UTS	OUTF	PUTS
OEA	OEB	An	Bn
L	L	INPUT	B=A
Н	L	Z	Z
L	Н	а	а
Н	Н	A=B	INPUT

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ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	−0.5 to V _{CC}	V
I _{OUT}	Current applied to output in Low output state	128	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	3	LIMITS				
STWIBUL	PARAMETER	MIN	NOM	MAX	UNIT		
V _{CC}	Supply voltage	4.5	5.0	5.5	V		
V _{IH}	High-level input voltage	2 .0			V		
V _{IL}	Low-level input voltage			0.8	V		
I _{IK}	Input clamp current			-18	mA		
I _{OH}	High-level output current			-15	mA		
I _{OL}	Low-level output current			64	mA		
T _{amb}	Operating free-air temperature range	0		70	°C		

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMET	ren		ST CONDITION	C1		LIMITS		
STWBUL	PARAME	IER	'5	SI CONDITION	MIN	TYP ²	MAX	UNIT	
			V _{CC} = MIN,		±10%V _{CC}	2.4			,,
	I limb to cal autout valta aa		$V_{IL} = MAX,$ $V_{IH} = MIN$ $I_{OH} = -3mA$ $\pm 5\% V_{CC}$		2.7	3.3		V	
V _{OH}	High-level output voltage)	V _{CC} = MIN,		±10%V _{CC}	2.0	3.2		
			V _{IL} = MAX, V _{IH} = MIN	$I_{OL} = -15 \text{mA}$	±5%V _{CC}	2.0	3.1		V
.,			V _{CC} = MIN,		±10%V _{CC}			0.55	,,
V _{OL}	Low-level output voltage		$V_{IL} = MAX,$ $V_{IH} = MIN$	I _{OH} =MAX	±5%V _{CC}		0.42	0.55	· V
V _{IK}	Input clamp voltage	Input clamp voltage					-0.73	-1.2	V
lı .	Input current at	A0-A3, B0-B3	V _{CC} = MAX,	V _I = 5.5V	0			1	mA
'1	maximum input voltage	ŌĒ _A , OE _B	$V_{CC} = MAX, Y$	$V_{CC} = MAX, V_I = 7.0V$				100	μΑ
I _{IH}	High-level input current	OE _A , OE _B	$V_{CC} = MAX,$	V _{CC} = MAX, VI = 2.7V				20	μΑ
I _{IL}	Low-level input current	only	V _{CC} = MAX,	VI = 0.5V	-			-1	mA
I _{IH} +I _{OZH}	Off-state output current High-level voltage applie	ed	V _{CC} = MAX,	V _O = 2.7V	14.			70	μА
	Off-state output current	74F242		0.51/				-1.0	,
I _{IL} +I _{OZL}	Low-level voltage applied	74F243	$V_{CC} = MAX, $	V _O = 0.5 V				-1.6	mA
Ios	Short-circuit output curre	ent ³	$V_{CC} = MAX$			-100		-225	mA
		Іссн					22	35	mA
		74F242 I _{CCL}	$V_{CC} = MAX$				40	55	mA
	County assessed (to to 1)	lccz]				32	45	mA
I _{CC}	Supply current (total)	Іссн					64	80	mA
		74F243 I _{CCL}	$V_{CC} = MAX$				64	90	mA
		I _{CCZ}					71	90	mA

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

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All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

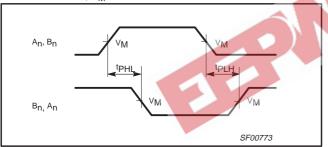
Transceivers 74F242/74F243

AC ELECTRICAL CHARACTERISTICS

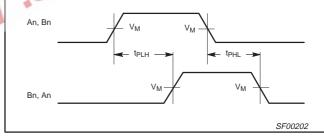
						LIM	ITS		
SYMBOL	PARAMETER		TEST CONDITION	l T _a	/ _{CC} = +5\ _{mb} = +25 0pF, R _L =	°C	V _{CC} = +5 T _{amb} = 0°C C _L = 50pF,	iV ± 10% C to +70°C R _L = 500Ω	UNIT
				MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay An, Bn to Bn, An		Waveform NO TAG	2.5 2.0	3.5 3.0	6.0 4.5	2.5 2.0	7.0 4.5	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level	74F242	Waveform 3 Waveform 4	3.0 3.5	4.0 6.5	7.0 9.0	3.0 3.5	8.0 10.5	ns
t _{PHZ} t _{PLZ}	Output Disable time from High or Low level		Waveform 3 Waveform 4	3.5 3.5	5.5 6.0	8.5 9.5	3.5 3.5	9.0 11.0	ns
t _{PLH} t _{PHL}	Propagation delay An, Bn to Bn, An		Waveform 2	2.5 2.5	4.0 4.0	5.2 5.2	2.0 2.0	6.2 6.5	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level	74F243	Waveform 3 Waveform 4	2.0 2.0	4.5 5.0	5.7 7. 5	2.0 2.0	6.7 8.5	ns
t _{PHZ}	Output Disable time from High or Low level		Waveform 3 Waveform 4	2.0 2.0	4.0 4.5	6.0 6.0	2.0 2.0	7.0 7.0	ns

AC WAVEFORMS

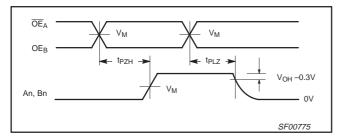
For all waveforms, $V_M = 1.5V$.



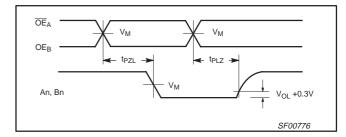
Waveform 1. For Inverting Outputs



Waveform 2. For Non-Inverting Outputs



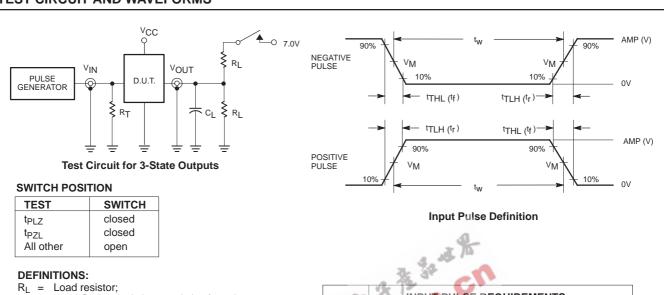
Waveform 3. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 4. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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TEST CIRCUIT AND WAVEFORMS



DEFINITIONS:

R_L = Load resistor;
see AC electrical characteristics for value.

C_L = Load capacitance includes jig and probe capacitance;
see AC electrical characteristics for value.

Termination resistance should be equal to Z_{OUT} of pulse generators.

	INPUT PULSE REQUIREMENTS									
family amplitude V	rep. rate	t _w	t _{TLH}	t _{THL}						
74F 3.0V 1.5	V 1MHz	500ns	2.5ns	2.5ns						

SF00777

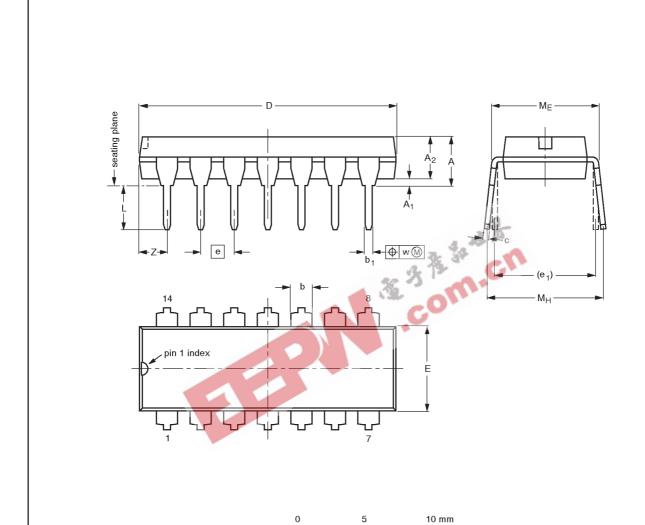
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Transceivers

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

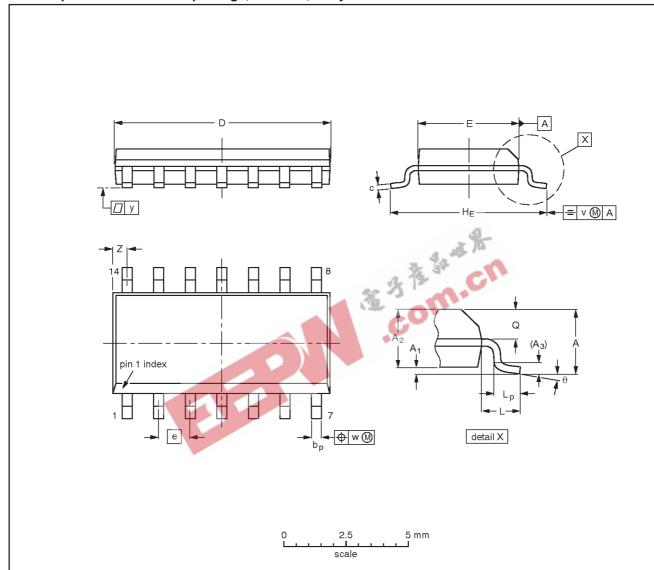
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT27-1	050G04	MO-001AA			92-11-17 95-03-11

Transceivers

74F242, 74F243

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

DIMENTO																		
UNIT	A max.	Α1	A ₂	Α3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE	
SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22	

Transceivers 74F242, 74F243

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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